TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC4051BP, TC4051BF, TC4051BFN, TC4051BFT TC4052BP, TC4052BF, TC4052BFN, TC4052BFT TC4053BP, TC4053BF, TC4053BFN, TC4053BFT

TC4051B

Single 8-Channel Multiplexer/Demultiplexer

TC4052B

Differential 4-Channel Multiplexer/Demultiplexer

TC4053B

Triple 2-Channel Multiplexer/Demultiplexer

TC4051B, TC4052B and TC4053B are multiplexers with capabilities of selection and mixture of analog signal and digital signal. TC4051B has 8 channels configuration. TC4052B has 4 channel × 2 configuration and TC4053B has 2 channel × 3 configuration. The digital signal to the control terminal turns "ON" the corresponding switch of each channel, with large amplitude (VDD – VEE) can be switched by the control signal with small logical amplitude (VDD – VSS). For example, in the case of VDD = 5 V VSS = 0 V and VEE = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with single power supply of 5 volts. As the ON-resistance of each switch is low, these can be connected to the circuits with low input impedance.



Pin Assignment







Truth Table

Control Inputs				"ON" Channel					
Inhibit	CΔ	В	А	TC4051B	TC4052B	TC4053B			
L	L	L	L	0	0X, 0Y	0X, 0Y, 0Z			
L	L	L	Н	1	1X, 1Y	1X, 0Y, 0Z			
L	L	Н	L	2	2X, 2Y	0X, 1Y, 0Z			
L	L	Н	Н	3	3X, 3Y	1X, 1Y, 0Z			
L	Н	L	L	4	—	0X, 0Y, 1Z			
L	Н	L	Н	5	—	1X, 0Y, 1Z			
L	Н	Н	L	6	—	0X, 1Y, 1Z			
L	Н	Н	Н	7	_	1X, 1Y, 1Z			
Н	Х	Х	Х	None	None	None			

X: Don't care

Δ: Except TC4052B

Logic Diagram

TC4051B



TC4052B



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TC4053B



Truth Table

Control C	Impedance between IN-OUT	(Note)
Н	0.5 to 5 \times 10 2 Ω	
L	>10 ⁹ Ω	

Note: See electrical characteristics

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
DC supply voltage	V _{DD} -V _{SS}	-0.5 to 20	V
DC supply voltage	V _{DD} -V _{EE}	-0.5 to 20	V
Control input voltage	VCIN	$V_{SS}{-}0.5$ to $V_{DD}{+}0.5$	V
Switch I/O voltage	VI/VO	$V_{\mbox{\scriptsize EE}}-0.5$ to $V_{\mbox{\scriptsize DD}}+0.5$	V
Control input current	ICIN	±10	mA
Potential difference across I/O during ON	VI-VO	-0.5 to 0.5	V
Power dissipation	PD	300 (DIP)/180 (SOIC)	mW
Operating temperature range	Topr	-40 to 85	°C
Storage temperature range	T _{stg}	–65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	V _{DD} -V _{SS}	—	3	_	18	v
DC supply voltage	V _{DD} -V _{EE}		3	_	18	
Control input voltage	V _{IN}		V _{SS}	_	V _{DD}	V
Input/output voltage	VIN/VOUT		V _{EE}	_	V _{DD}	V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused Control inputs must be tied to either V_{DD} or V_{SS} .

Static Electrical Characteristics

		Test Condition				-40°C			25°C		85			
Characteristics	Symbol		V _{SS} (V)	V _{EE} (V)	V _{DD} (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit	
					5	3.5	_	3.5	2.75	—	3.5	_		
Control input high voltage	VIH		$V_{EE} = V_{SS}$	10	7.0		7.0	5.50	—	7.0	—	V		
		$V_{IS} = V_{DD}$	$R_L = 1 K\Omega$ to V_{SS}		15	11.0		11.0	8.25	—	11.0	—		
		thru 1 kΩ	I _{IS} < 2	2 μΑ	5	_	1.5	_	2.25	1.5	_	1.5		
Control input low voltage	V_{IL}		on all chanr	OFF	10		3.0	—	4.5	3.0	—	3.0	V	
			Channels		15	_	4.0	—	6.75	4.0	—	4.0		
			0	0	5	_	850	_	240	950	_	1200		
On-state resistance	R _{ON}	$0 \ge v_{\rm IS} \ge v_{\rm DD}$	0	0	10	_	210	—	110	250	—	300	Ω	
		RL = 10 Ksz	0	0	15	_	140	—	80	160	—	200		
∆On-state	R _{ON} ∆		0	0	5	_		_	10	_	_	—		
resistance between any 2		_	0	0	10	_		—	6	—	—	—	Ω	
switches			0	0	15			—	4	—	—	—		
Input/output	IOFF	V _{IN} = 18 V, V _{OUT} = 0 V V _{IN} = 0 V, V _{OUT} = 18 V			18		±100	_	±0.01	±100	_	±1000	nA	
leakage current					18		±100	_	±0.01	±100	—	±1000		
	I _{DD}		(Note)		5	_	5.0	_	0.005	5.0		150		
Quiescent supply		$V_{IN} = V_{SS}, V_{DD}$			10		10		0.010	10	_	300	μA	
ouriont					15		20	—	0.015	20	_	600		
	I _{IN}	V _{IH} = 18 V V _{IL} = 0 V			18	_	0.1	_	10 ⁻⁵	0.1	_	1.0		
Input current					18	_	-0.1	_	-10 ⁻⁵	-0.1	_	-1.0	μA	
Input capacitance	C _{IN}	_			—	_			5	7.5			pF	
Switch input capacitance	C _{IN}	_				_			10			_	pF	
		TC4051B			10	_	_	_	58	_	_	_		
Output	C _{OUT}	TC4052B			10	_		_	30	_	_	_	pF	
capacitance	20.	TC4053B			10	_		_	17	_	_			
		TC4051B			10	_		_	0.2	_	_	_		
Feedthrough	C _{IN} -	TC4052B			10	_		_	0.2	_	_	_	pF	
Capacitarice	C-OUT	TC4053B			10	_	_	_	0.2	_	_	—		

Note: All valid input combinations.

Dynamic Electrical Characteristics (Ta = $25^{\circ}C$, C_L = 50 pF)

		Те								
Characteristics	Symbol		V _{SS} (V)	V _{EE} (V)	V _{DD} (V)	Min	Тур.	Max	Unit	
				0	0	5	_	15	45	
Phase difference between	ф І-О	_		0	0	10	_	8	20	ns
				0	0	15	_	6	15	
				0	0	5		170	550	
Dreneration delay time	^t pZL			0	0	10	_	90	240	
	чрZН	$R_L = 1 \ k\Omega$		0	0	15	_	70	160	ns
(A, B, C, -OUT)	^l pLZ			0	-5	5	_	100	240	
	^т рНZ			0	-7.5	7.5	_	80	160	
				0	0	5	_	120	380	
Dropogation dology time	+			0	0	10	_	60	200	
	۹ ۲ ۲	$R_L = 1 \ k\Omega$		0	0	15	_	50	160	ns
(INH-OUT)	ιрΖΗ			0	-5	5	_	80	200	
				0	-7.5	7.5	_	60	160	
				0	0	5		170	450	
Dreneration delay time	t _{pLZ} t _{pHZ}			0	0	10	_	90	210	ns
		$R_L = 1 \ k\Omega$		0	0	15	_	70	160	
				0	-5	5	_	100	210	
				0	-7.5	7.5		80	160	
-3dB cutoff frequency				-5	-5	5		20		
TC4051B	f _{max} (I-O)	$R_L = 1 \ k\Omega$	(Note 1)	-5	-5	5	_	30	_	MHz
TC4052B				-5	-5	5	_	40	_	
TC4053B										
		$R_L = 10 \ k\Omega$		-2.5	-2.5	2.5	_	0.15	—	
Total harmonic distortion	—	f = 1 kHz	(Note 2)	-5	-5	5	_	0.03	—	%
				-7.5	-7.5	7.5	_	0.02		
-50dB feedthrough	_	$R_L = 1 k\Omega$	(Note 3)	-5	-5	5	_	500	_	kHz
(switch off)										
Crosstalk	—	$R_L = 1 k\Omega$	(Note 4)	-5	-5	5		1.5		MHz
Crosstalk	_	$R_{IN} = 1 \ k\Omega$		0	0	5	—	200	—	
(control-OUT)		$R_{OUT} = 10 \ k\Omega$		0	0	10	—	400	—	mV
· · · ·		$C_L = 15 \text{ pF}$		0	0	15		600	—	

Note 1: Sine wave of $\pm 2.5 V_{p-p}$ shall be used for V_{is} and the frequency of 20 log 10 $\frac{V_{OS}}{V_{is}} = -3dB$ shall be f_{max}.

Note 2: V_{is} shall be sine wave of
$$\pm \left(\frac{V_{DD} - V_{EE}}{4}\right) p-p$$
.

Note 3: Sine wave of $\pm 2.5 \text{ V}_{p-p}$ shall be used for V_{is} and the frequency of 20 log 10 $\frac{V_{OS}}{V_{is}} = -50 \text{dB}$ shall be feed-through.

Note 4: Sine wave of $\pm 2.5 V_{p-p}$ shall be used for V_{is} and the frequency of 20 log 10 $\frac{V_{OS}}{V_{is}} = -50$ dB shall be crosstalk.

Package Dimensions



Weight: 1.00 g (typ.)

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Package Dimensions

SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN

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